**Product data sheet** 

## 1. Product profile

### 1.1 General description

Passivated sensitive gate Silicon-Controlled Rectifier (SCR) in a SOT54 plastic package

#### 1.2 Features

- Direct interfacing to logic level ICs
- Direct interfacing to low-power gate drive circuits
- For operation on DC and rectified AC supplies

### 1.3 Applications

- Christmas lights control
- Protection and safety shutdown circuits e.g. lighting ballasts

### 1.4 Quick reference data

- $V_{DRM} \leq 400 \text{ V}$
- $I_{TSM} \le 8 \text{ A (t = 10 ms)}$
- $I_{T(RMS)} \le 0.8 A$
- $I_{T(AV)} \le 0.5 A$

## 2. Pinning information

Table 1. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	anode (A)		. 81
2	gate (G)		A - K
3	cathode (K)		G sym037
		SOT54 (TO-92)	



**SCR logic level** 

# 3. Ordering information

### Table 2. Ordering information

Type number	Package					
	Name	Description	Version			
NXL0840	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54			

# 4. Limiting values

### Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Parameter	Conditions	Min	Max	Unit
repetitive peak off-state voltage		-	400	V
average on-state current	half sine wave; $T_{lead} \le 83 ^{\circ}\text{C}$ ; see Figure 1	-	0.5	Α
RMS on-state current	all conduction angles; see <u>Figure 4</u> and <u>5</u>	-	0.8	Α
non-repetitive peak on-state current	half sine wave; $T_j = 25$ °C prior to surge; see Figure 2 and 3			
	t = 10 ms	-	8	А
	t = 8.3 ms	-	9	Α
I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms	-	0.32	A <sup>2</sup> s
rate of rise of on-state current	$I_{TM} = 2 \text{ A}; I_G = 10 \text{ mA};$ $dI_G/dt = 100 \text{ mA}/\mu\text{s}$	-	50	A/μs
peak gate current		-	1	А
peak gate voltage		-	5	V
peak reverse gate voltage		-	5	V
peak gate power		-	2	W
average gate power	over any 20 ms period	-	0.1	W
storage temperature		-40	+150	°C
junction temperature		-	125	°C
	repetitive peak off-state voltage average on-state current  RMS on-state current  non-repetitive peak on-state current  I²t for fusing rate of rise of on-state current  peak gate current peak gate voltage peak reverse gate voltage peak gate power average gate power storage temperature	repetitive peak off-state voltage	repetitive peak off-state voltage average on-state current half sine wave; $T_{lead} \le 83  ^{\circ}\text{C}$ ; see Figure 1 all conduction angles; see Figure 4 and 5 half sine wave; $T_j = 25  ^{\circ}\text{C}$ prior to surge; see Figure 2 and 3 te = 10 ms te = 8.3 ms te = 10 mA; te = 10 mA; te = 10 mA; te = 10 mA/ $\mu$ s te = 10 m	repetitive peak off-state voltage $-400$ average on-state current half sine wave; $T_{lead} \le 83  ^{\circ}\text{C}$ ; $-30.5$ see Figure 1 all conduction angles; see Figure 4 and 5 half sine wave; $T_j = 25  ^{\circ}\text{C}$ prior to surge; see Figure 2 and 3 $-30.32  ^{\circ}$ to $-30.32  ^{\circ$

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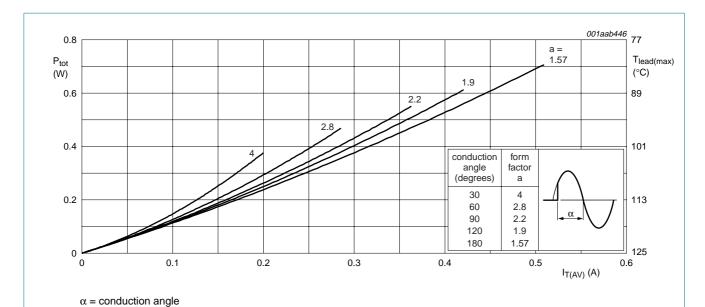
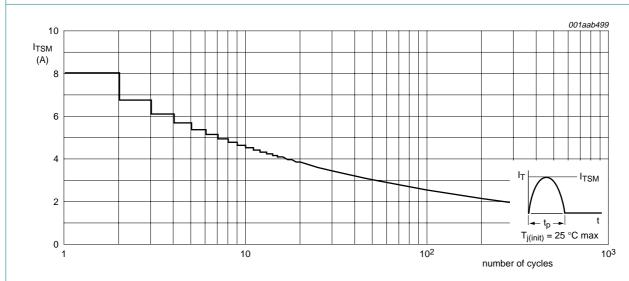


Fig 1. Total power dissipation as a function of average on-state current; maximum values



f = 50 Hz

Fig 2. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

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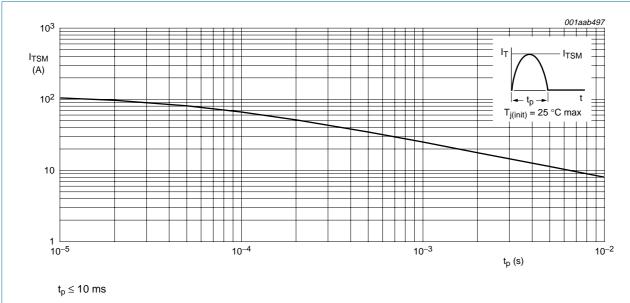


Fig 3. Non-repetitive peak on-state current as a function of pulse width; maximum values

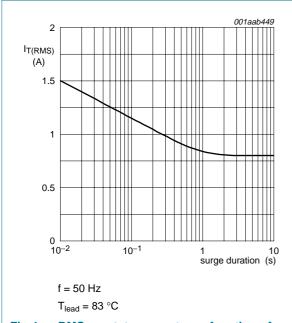


Fig 4. RMS on-state current as a function of surge duration; maximum values

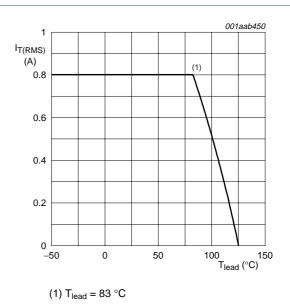


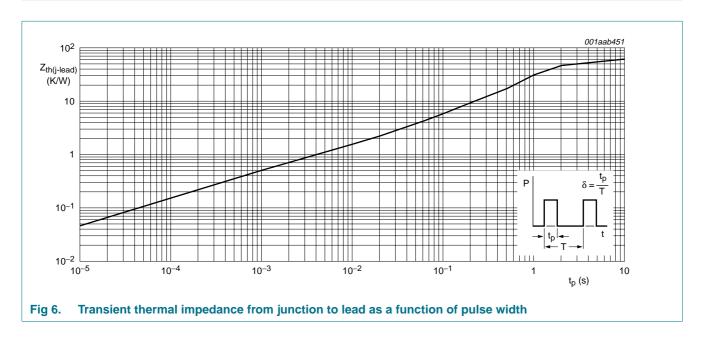
Fig 5. RMS on-state current as a function of lead temperature; maximum values

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## 5. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-lead)}}$	thermal resistance from junction to lead	see Figure 6	-	-	60	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	printed circuit board mounted; lead length 4 mm	-	150	-	K/W



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## 6. Characteristics

Table 5. Characteristics

 $T_i = 25 \,^{\circ}C$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	naracteristics		'	'	· ·	'
I <sub>GT</sub>	gate trigger current	$V_D = 12 \text{ V}; I_T = 10 \text{ mA}; \text{see } \frac{\text{Figure 8}}{\text{M}}$	-	50	200	μΑ
IL	latching current	$V_D$ = 12 V; $I_G$ = 0.5 mA; $R_{GK}$ = 1 k $\Omega$ ; see Figure 10	-	2	6	mA
I <sub>H</sub>	holding current	$V_D$ = 12 V; $I_G$ = 0.5 mA; $R_{GK}$ = 1 k $\Omega$ ; see Figure 11	-	2	5	mA
$V_{T}$	on-state voltage	I <sub>T</sub> = 1.2 A; see <u>Figure 9</u>	-	1.25	1.7	V
$V_{GT}$	gate trigger voltage	I <sub>T</sub> = 10 mA; see <u>Figure 7</u>				
		V <sub>D</sub> = 12 V	-	0.5	0.8	V
		$V_D = V_{DRM(max)}$ ; $T_j = 125  ^{\circ}C$	0.2	0.3	-	V
I <sub>D</sub>	off-state current	$V_D = V_{DRM(max)}$ ; $T_j = 125$ °C; $R_{GK} = 1 \text{ k}\Omega$	-	0.05	0.1	mΑ
Dynamic	c characteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 0.67 × $V_{DRM(max)}$ ; $T_j$ = 125 °C; exponential waveform; see Figure 12				
		$R_{GK} = 1 k\Omega$	200	600	-	V/μs
		gate open circuit	-	25		V/μs

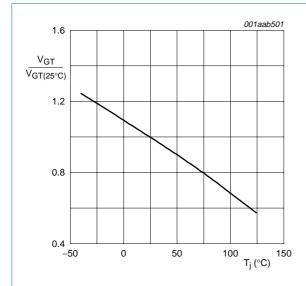


Fig 7. Normalized gate trigger voltage as a function of junction temperature

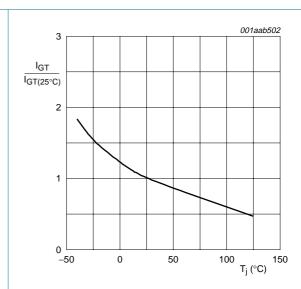
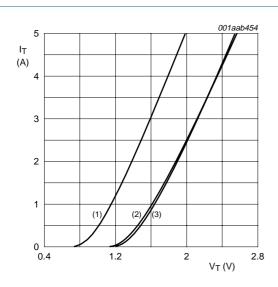


Fig 8. Normalized gate trigger current as a function of junction temperature

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 $V_0 = 1.067 \text{ V}$ 

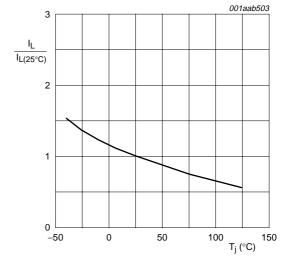
 $R_s = 0.187 \Omega$ 

(1)  $T_i = 125$  °C; typical values

(2)  $T_i = 125 \,^{\circ}C$ ; maximum values

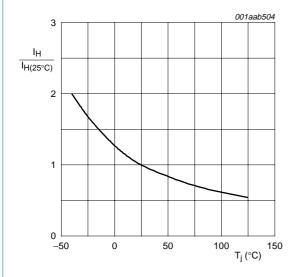
(3)  $T_j = 25$  °C; maximum values

Fig 9. On-state current as a function of on-state voltage



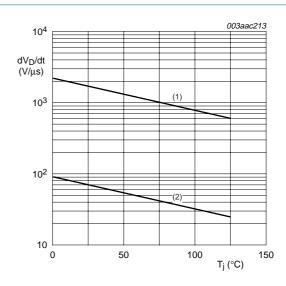
 $R_{GK} = 1 k\Omega$ 

Fig 10. Normalized latching current as a function of junction temperature



 $R_{GK} = 1 k\Omega$ 

Fig 11. Normalized holding current as a function of junction temperature



(1)  $R_{GK} = 1 k\Omega$ 

(2) Gate open-circuit

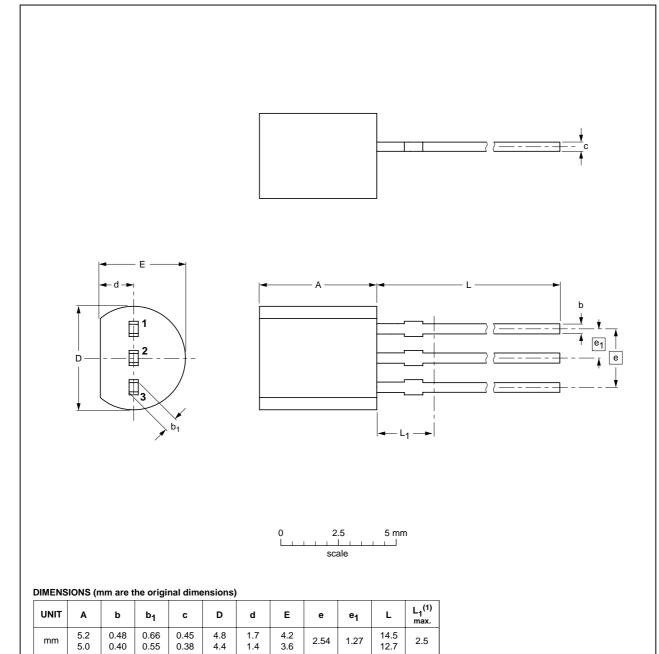
Fig 12. Critical rate of rise of off-state voltage as a function of junction temperature; typical values

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## 7. Package outline

# Plastic single-ended leaded (through hole) package; 3 leads

SOT54



#### Note

<sup>1.</sup> Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE		REFER	REFERENCES EUROPEAN ISSUE		EUROPEAN	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT54		TO-92	SC-43A			<del>04-06-28</del> 04-11-16

Fig 13. Package outline SOT54 (TO-92)

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# 8. Revision history

### Table 6. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NXL0840_1	20080226	Product data sheet	-	-

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## 9. Legal information

#### 9.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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# **NXL0840**

**SCR logic level** 

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